

## Application Data Sheet

### **Application Information**

Application Type:: Regular  
Subject Matter:: Utility  
Suggested Group Art Unit:: N/A  
CD-ROM or CD-R?:: None  
Sequence submission?:: None  
Computer Readable Form (CRF)?:: No  
Title:: MULTILEVEL SEMICONDUCTOR  
MEMORY, WRITE/READ METHOD  
THERETO/THEREFROM AND STORAGE  
MEDIUM STORING WRITE/READ  
PROGRAM  
Attorney Docket Number:: 21737-00013-US5  
Request for Early Publication?:: No  
Request for Non-Publication?:: No  
Total Drawing Sheets:: 10  
Small Entity?:: No  
Petition included?:: No  
Secrecy Order in Parent Appl.?:: No

### **Applicant Information**

Applicant Authority Type:: Inventor  
Primary Citizenship Country:: Japan  
Status:: Full Capacity  
Given Name:: Katsuki  
Family Name:: Hazama  
City of Residence:: Tokyo-to  
Country of Residence:: Japan  
Street of mailing address:: c/o Nippon Steel Corporation  
6-3, Otemachi 2-chome

City of mailing address:: Chiyoda-ku, Tokyo-to

State or Province of mailing address::

Country of mailing address:: Japan

### **Correspondence Information**

Correspondence Customer Number:: 30678

### **Representative Information**

Representative Customer Number:: 30678

### **Domestic Priority Information**

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This Application	Divisional of	09/438,295	11/12/1999
This Application	Divisional of	08/931,519	09/16/1997

### **Foreign Priority Information**

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	267844	09/18/96	Yes
Japan	342663	12/06/96	Yes

### **Assignee Information**

Assignee name:: Nippon Steel Corporation  
6-3, Otemachi 2-chome  
Chiyoda-ku, Tokyo-to, JAPAN